



PJQ4476AP-AU

100V N-Channel Enhancement Mode MOSFET

Voltage 100 V **Current** 35 A

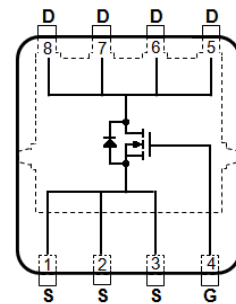
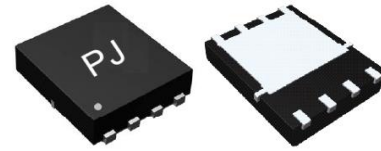
Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@15A < 25m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@10A < 28.5m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.001 ounces, 0.03 grams

DFN3333-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS |
|---|-------------------------|-----------------|----------|--------------------|
| Drain-Source Voltage | | V_{DS} | 100 | V |
| Gate-Source Voltage | | V_{GS} | ± 20 | |
| Continuous Drain Current ^(Note 4) | $T_C=25^\circ\text{C}$ | I_D | 35 | A |
| | $T_C=100^\circ\text{C}$ | | 22 | |
| Pulsed Drain Current ^(Note 1) | $T_C=25^\circ\text{C}$ | I_{DM} | 140 | |
| Power Dissipation | $T_C=25^\circ\text{C}$ | P_D | 62 | W |
| | $T_C=100^\circ\text{C}$ | | 25 | |
| Continuous Drain Current ^(Note 4) | $T_A=25^\circ\text{C}$ | I_D | 6.3 | A |
| | $T_A=70^\circ\text{C}$ | | 5 | |
| Power Dissipation | $T_A=25^\circ\text{C}$ | P_D | 2.0 | W |
| | $T_A=70^\circ\text{C}$ | | 1.3 | |
| Single Pulse Avalanche Energy ^(Note 6) | | E_{AS} | 54 | mJ |
| Operating Junction and Storage Temperature Range | | T_J, T_{STG} | -55~150 | $^\circ\text{C}$ |
| Typical Thermal Resistance ^(Note 4,5) | Junction to Case | $R_{\theta JC}$ | 2 | $^\circ\text{C/W}$ |
| | Junction to Ambient | $R_{\theta JA}$ | 62.5 | |



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Electrical Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|---|---------------------|---|--|------|------|-------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250uA | 100 | - | - | V |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =250uA | 1 | 1.73 | 2.5 | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =10V, I _D =15A | - | 20 | 25 | mΩ |
| | | V _{GS} =4.5V, I _D =10A | - | 22 | 28.5 | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =80V, V _{GS} =0V | - | - | 1 | uA |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} =±20V, V _{DS} =0V | - | - | ±100 | nA |
| Dynamic (Note 5) | | | | | | |
| Total Gate Charge | Q _g | V _{DS} =50V, I _D =10A, V _{GS} =10V (Note 2,3) | - | 31 | - | nC |
| Gate-Source Charge | Q _{gs} | | - | 5.1 | - | |
| Gate-Drain Charge | Q _{gd} | | - | 7.3 | - | |
| Input Capacitance | C _{iss} | V _{DS} =30V, V _{GS} =0V, f=1MHZ | - | 1519 | - | pF |
| Output Capacitance | C _{oss} | | - | 132 | - | |
| Reverse Transfer Capacitance | C _{rss} | | - | 66 | - | |
| Turn-On Delay Time | t _{d(on)} | | V _{DD} =50V, I _D =10A, V _{GS} =10V, R _G =3Ω (Note 2,3) | - | 11 | |
| Turn-On Rise Time | t _r | - | | 42 | - | |
| Turn-Off Delay Time | t _{d(off)} | - | | 40 | - | |
| Turn-Off Fall Time | t _f | - | | 19 | - | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source Diode Forward Current | I _S | --- | - | - | 35 | A |
| Reverse Recovery Time | V _{SD} | I _S =1A, V _{GS} =0V | - | 0.68 | 1.2 | V |

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J = 25°C.
4. The maximum current rating is package limited.
5. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz. square pad of copper.
6. The test condition is L=3mH, I_{AS}=6A, V_{DD}=50V, V_{GS}=10V, Starting T_J=25°C.
7. Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

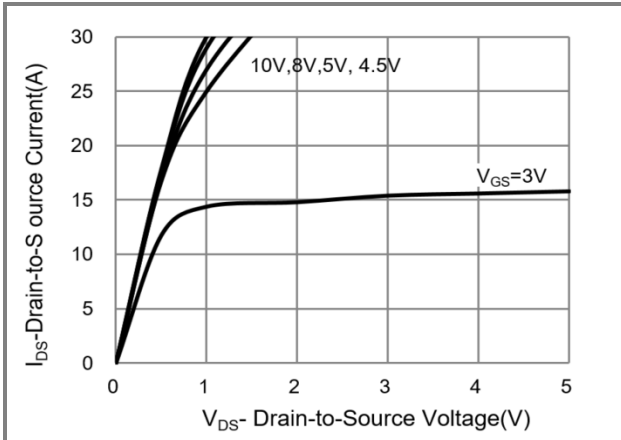


Fig.1 On-Region Characteristics

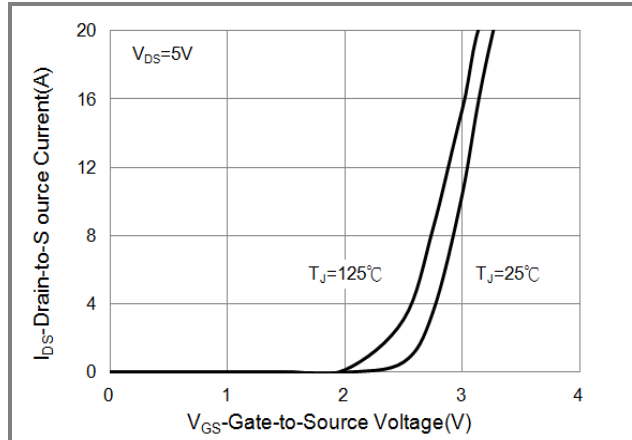


Fig.2 Transfer Characteristics

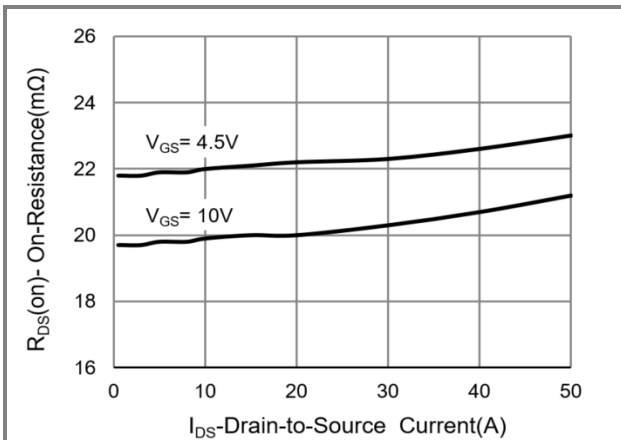


Fig.3 On-Resistance vs. Drain Current

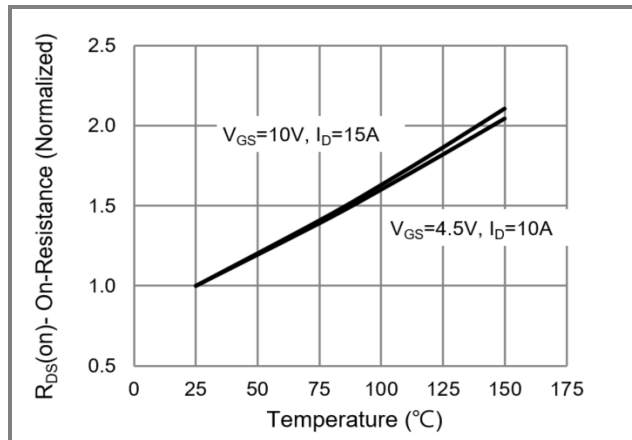


Fig.4 On-Resistance vs. Junction temperature

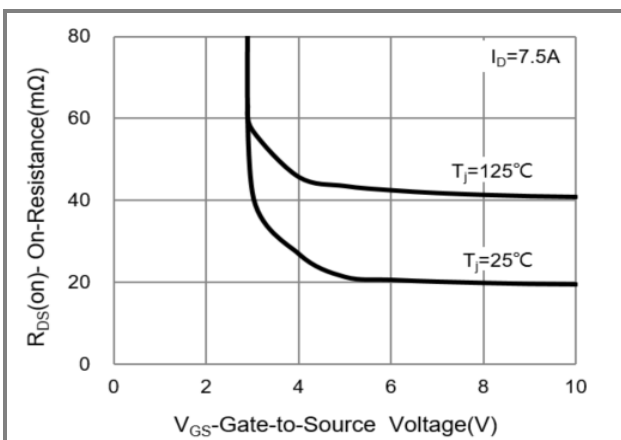


Fig.5 On-Resistance Variation with VGS

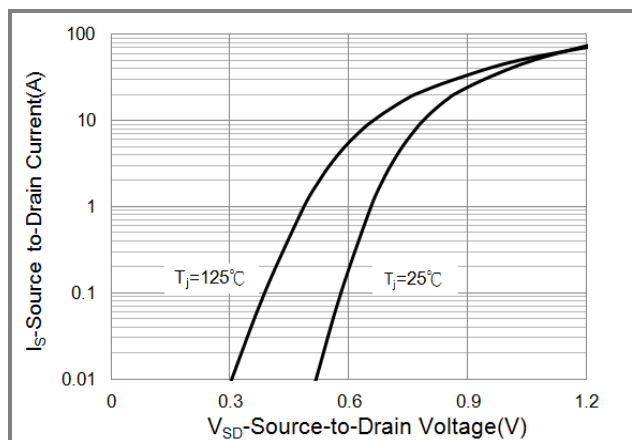


Fig.6 Source-Drain Diode Forward Voltage



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TYPICAL CHARACTERISTIC CURVES

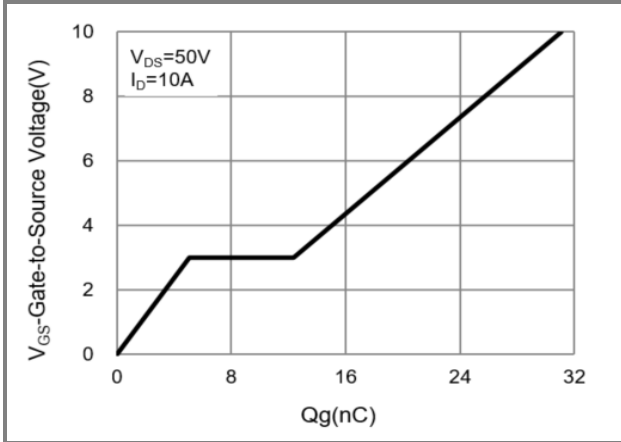


Fig.7 Gate-Charge Characteristics

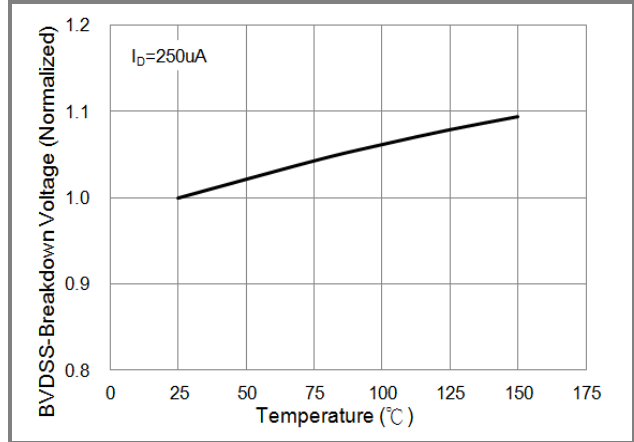


Fig.8 Breakdown Voltage Variation vs. Temperature

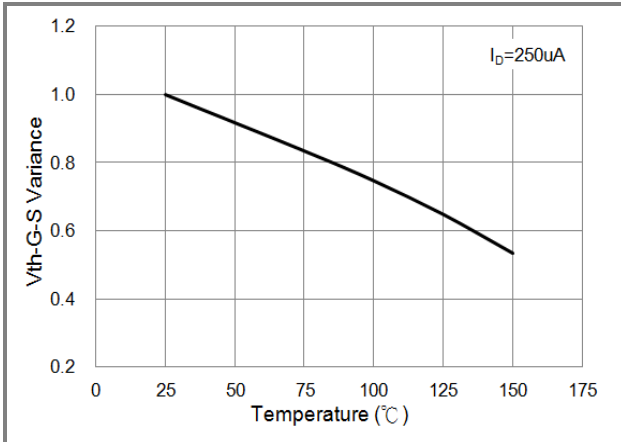


Fig.9 Threshold Voltage Variation with Temperature

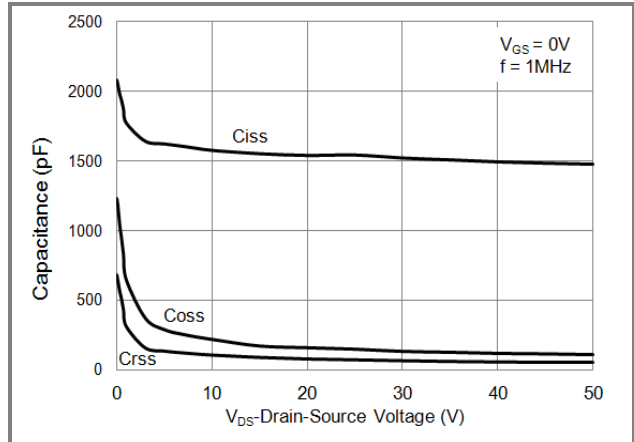


Fig.10 Capacitance vs. Drain-Source Voltage

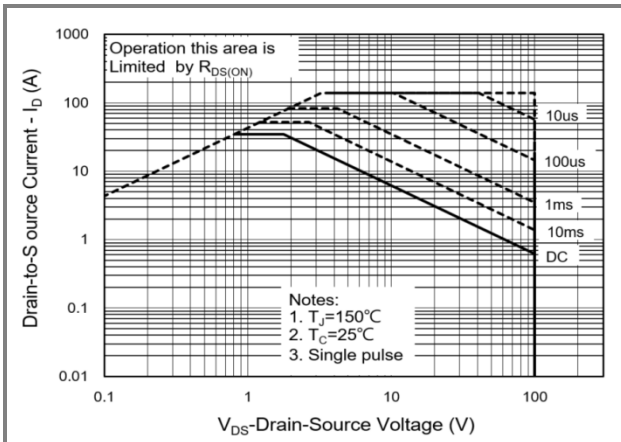


Fig.11 Maximum Safe Operating Area

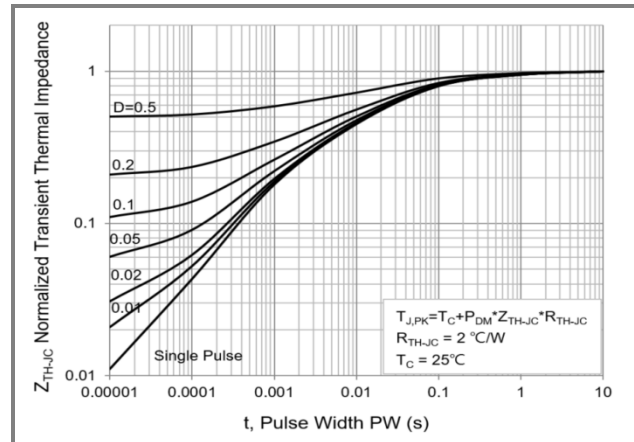


Fig.12 Normalized Transient Thermal Impedance

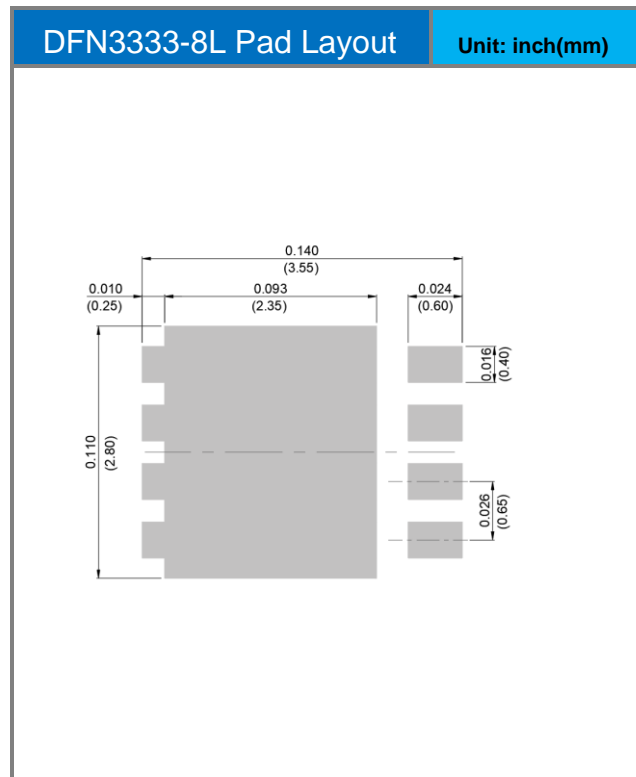
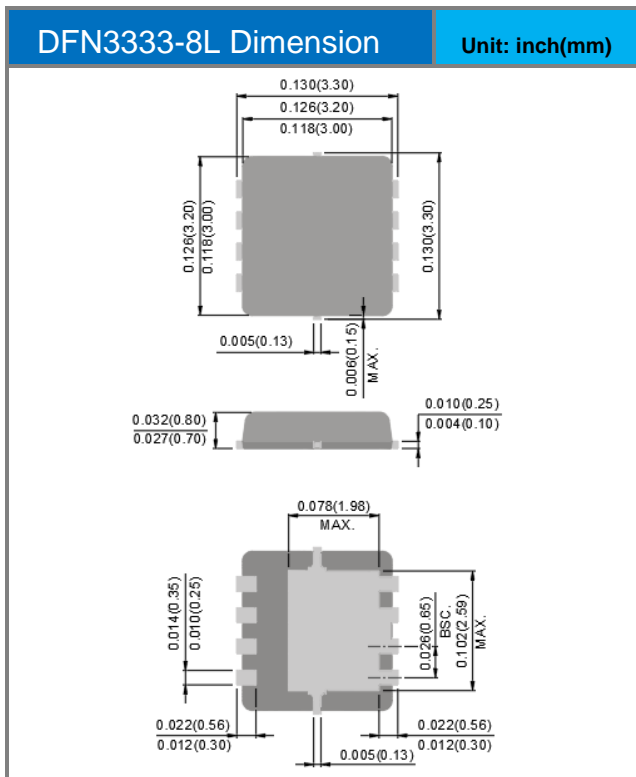


PJQ4476AP-AU

Part No. Packing Code Version

| Part No. Packing Code | Package Type | Packing Type | Marking | Version |
|-----------------------|--------------|-------------------|---------|--------------------------------|
| PJQ4476AP-AU_R2_000A1 | DFN3333-8L | 5K pcs / 13" reel | 4476 | Halogen free RoHS compliant |

Packaging Information & Mounting Pad Layout





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